

### Features

- Split Gate Trench MOSFET Technology
- Excellent Package for Heat Dissipation
- High Density Cell Design for Low  $R_{DS(on)}$
- Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1
- Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

### Maximum Ratings

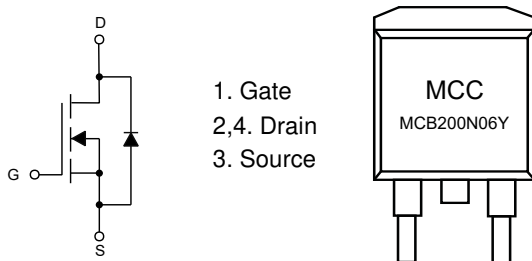
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 28°C/W Junction to Ambient<sup>(1)</sup>
- Thermal Resistance: 0.48°C/W Junction to Case

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	$V_{DS}$	60	V	
Gate-Source Voltage	$V_{GS}$	±20	V	
Continuous Drain Current <sup>(2)</sup>	$I_D$	$T_C=25^\circ C$	200	A
		$T_C=100^\circ C$	125	A
Pulsed Drain Current <sup>(3)</sup>	$I_{DM}$	600	A	
Avalanche Energy <sup>(4)</sup>	$E_{AS}$	500	mJ	
Total Power Dissipation <sup>(5)</sup>	$P_D$	260	W	

Note:

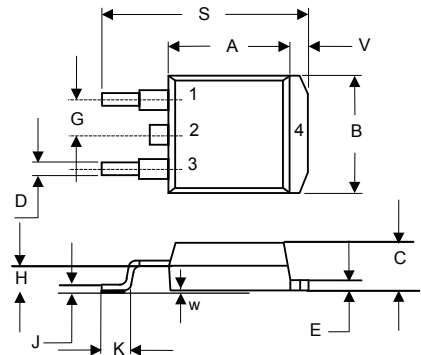
1. The value of  $R_{\theta JA}$  is measured with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz. copper, in a still air environment with  $T_A=25^\circ C$ .
2. The maximum current rating is package limited.
3. Repetitive rating; pulse width limited by max. junction temperature.
4.  $V_{DD}=50V$ ,  $R_G=25\Omega$ ,  $L=0.5mH$ , starting  $T_J=25^\circ C$ .
5.  $P_D$  is based on max. junction temperature, using junction-case thermal resistance.

### Internal Structure and Marking Code



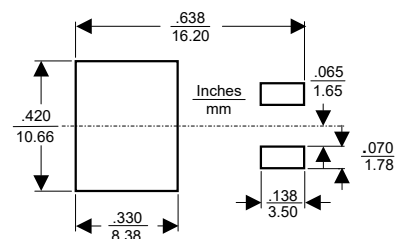
## N-CHANNEL MOSFET

### D2-PAK



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.331	0.370	8.40	9.40	
B	0.378	0.417	9.60	10.60	
C	0.165	0.189	4.20	4.80	
D	0.027	0.037	0.68	0.94	
E	0.045	0.055	1.14	1.40	
G	0.010		2.54		TYP.
H	0.096	0.134	2.43	3.40	
J	0.011	0.025	0.28	0.64	
K	0.071	0.131	1.80	3.32	
S	0.575	0.625	14.60	15.87	
V	0.042	0.058	1.07	1.47	
W	0.000	0.010	0.00	0.25	

### Suggested Solder Pad Layout



**Electrical Characteristics @ 25°C (Unless Otherwise Specified)**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	60			V
Gate-Source Leakage Current	$I_{GSS}$	$V_{DS}=0V, V_{GS}=\pm 20V$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=60V, V_{GS}=0V$			1	$\mu A$
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.2	1.8	2.2	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=20A$		2.35	2.6	m $\Omega$
		$V_{GS}=4.5V, I_D=15A$		2.9	3.6	m $\Omega$
<b>Diode Characteristics</b>						
Continuous Body Diode Current	$I_S$				200	A
Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V, I_S=20A$			1.2	V
Reverse Recovery Time	$t_{rr}$	$I_S=25A, di/dt=100A/\mu s$		68		ns
Reverse Recovery Charge	$Q_{rr}$			73		nC
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V, f=100KHz$		5950		pF
Output Capacitance	$C_{oss}$			1250		
Reverse Transfer Capacitance	$C_{rss}$			85		
Total Gate Charge	$Q_g$	$V_{DS}=50V, V_{GS}=10V, I_D=50A$		93		nC
Gate-Source Charge	$Q_{gs}$			17		
Gate-Drain Charge	$Q_{gd}$			14		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V, V_{DD}=30V, I_D=25A, R_{GEN}=2\Omega$		22.5		ns
Turn-On Rise Time	$t_r$			6.7		
Turn-Off Delay Time	$t_{d(off)}$			80.3		
Turn-Off Fall Time	$t_f$			26.9		

**Curve Characteristics**

Fig. 1 - Typical Output Characteristics

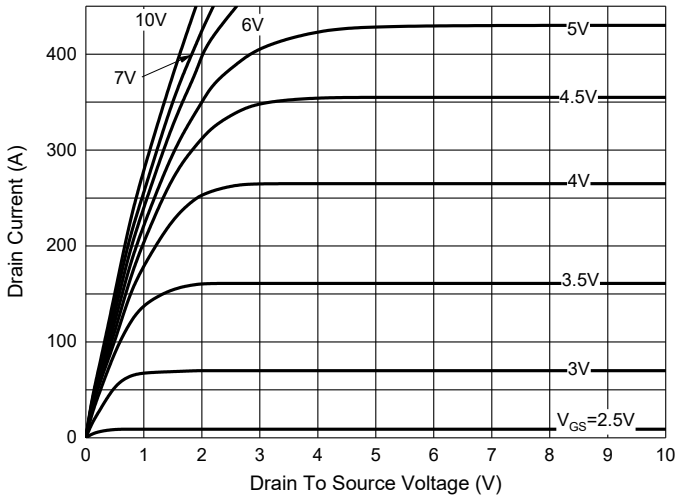


Fig. 2 -  $I_S - V_{SD}$

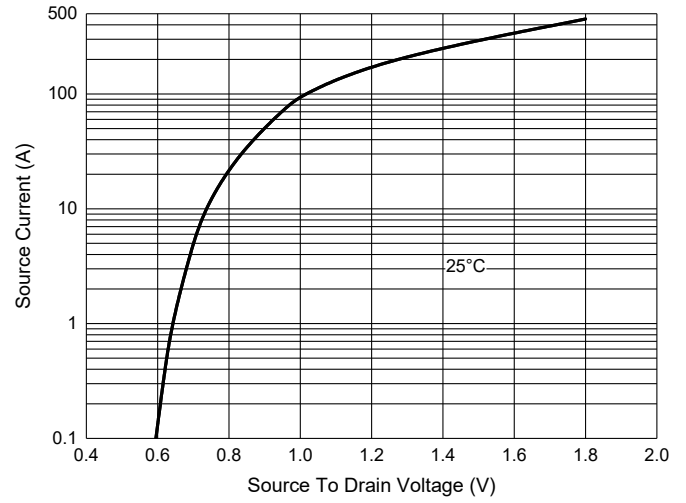


Fig. 3 -  $R_{DS(ON)} - I_D$

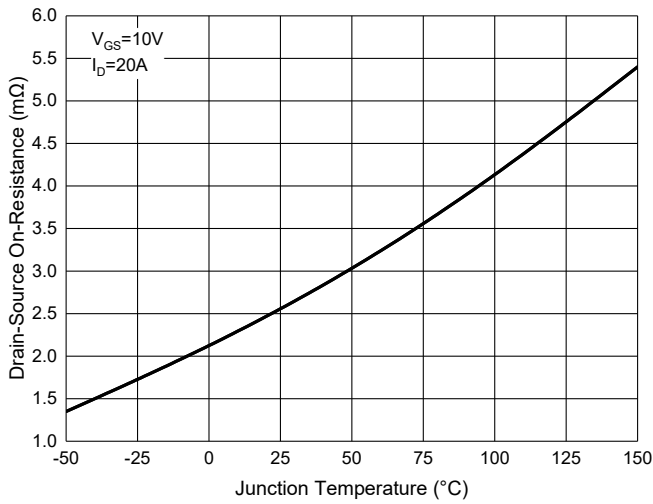


Fig. 4 - Capacitance Characteristics

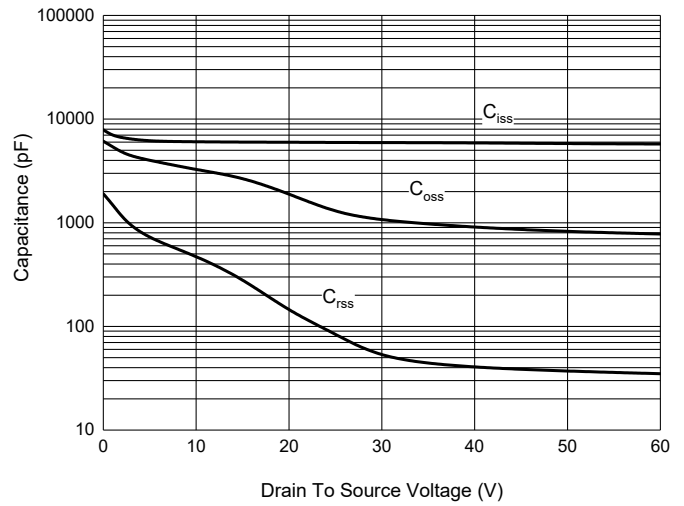


Fig. 5 - Gate Charge

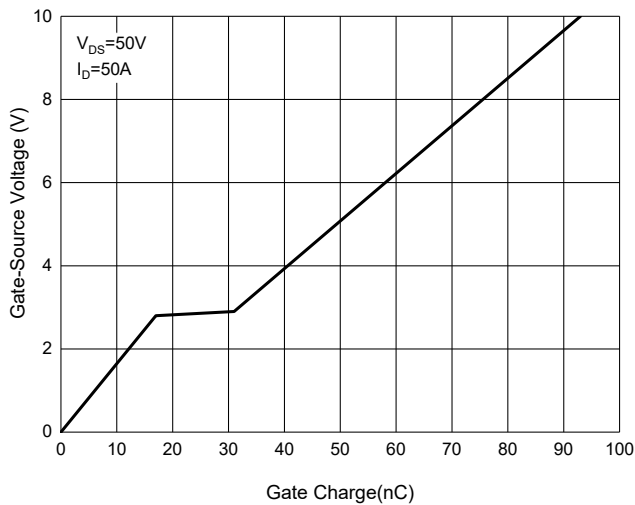
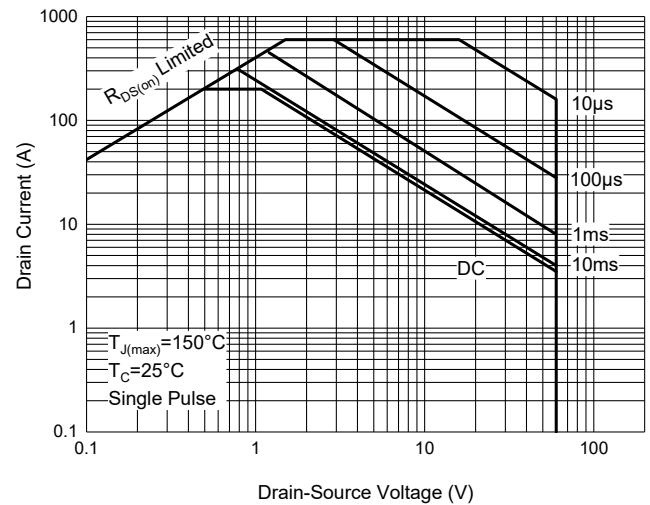


Fig. 6 - Safe Operation Area



## Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 800pcs/Reel
Part Number-BP	Tube: 5Kpcs/Ctn

Note : Adding "-HF" Suffix For Halogen Free, eg. Part Number-TP-HF

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